## BUH315D

## HIGH VOLTAGE FAST-SWITCHING NPN POWER TRANSISTOR

- STMicroelectronics PREFERRED SALESTYPE
- HIGH VOLTAGE CAPABILITY
- U.L. RECOGNISED ISOWATT218 PACKAGE (U.L. FILE \# E81734 (N))
- NPN TRANSISTOR WITH INTEGRATED FREEWHEELING DIODE.


## APPLICATIONS

- HORIZONTAL DEFLECTION FOR COLOUR TV


## DESCRIPTION

The BUH315D is manufactured using Multiepitaxial Mesa technology for cost-effective high performance and uses a Hollow Emitter structure to enhance switching speeds.
The BUH series is designed for use in horizontal deflection circuits in televisions and monitors.


INTERNAL SCHEMATIC DIAGRAM


## ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
| :---: | :--- | :---: | :---: |
| $\mathrm{V}_{\text {CBO }}$ | Collector-Base Voltage $\left(\mathrm{I}_{\mathrm{E}}=0\right)$ | 1500 | V |
| $\mathrm{~V}_{\mathrm{CEO}}$ | Collector-Emitter Voltage $\left(\mathrm{I}_{\mathrm{B}}=0\right)$ | 700 | V |
| $\mathrm{~V}_{\text {EBO }}$ | Emitter-Base Voltage $\left(\mathrm{I}_{\mathrm{C}}=0\right)$ | 10 | V |
| $\mathrm{I}_{\mathrm{C}}$ | Collector Current | 6 | A |
| $\mathrm{I}_{\mathrm{CM}}$ | Collector Peak Current $\left(\mathrm{t}_{\mathrm{p}}<5 \mathrm{~ms}\right)$ | 12 | A |
| $\mathrm{I}_{\mathrm{B}}$ | Base Current | 3 | A |
| $\mathrm{I}_{\mathrm{B}}$ | Base Peak Current $\left(\mathrm{t}_{\mathrm{p}}<5 \mathrm{~ms}\right)$ | 5 | A |
| $\mathrm{P}_{\text {tot }}$ | Total Dissipation at $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ | 44 | W |
| $\mathrm{~T}_{\text {stg }}$ | Storage Temperature | -65 to 150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{j}}$ | Max. Operating Junction Temperature | 150 | ${ }^{\circ} \mathrm{C}$ |

## THERMAL DATA

| $R_{\text {thj-case }}$ | Thermal Resistance Junction-case | Max | 2.8 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| :--- | :--- | :--- | :--- | :--- |

ELECTRICAL CHARACTERISTICS ( $\mathrm{T}_{\text {case }}=25^{\circ} \mathrm{C}$ unless otherwise specified)

| Symbol | Parameter | Test Conditions | Min. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Ices | Collector Cut-off Current ( V be $=0$ ) | $\mathrm{V}_{\text {CE }}=1500 \mathrm{~V}$ |  |  | 200 | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\text {ebo }}$ | Emitter Cut-off Current $(\mathrm{IC}=0)$ | $V_{\text {Eb }}=5 \mathrm{~V}$ | 110 |  | 300 | mA |
| $\mathrm{V}_{\text {CE(sat)* }}$ | Collector-Emitter Saturation Voltage | $\mathrm{IC}_{\mathrm{C}}=3 \mathrm{~A} \quad \mathrm{I}_{\mathrm{B}}=1 \mathrm{~A}$ |  |  | 1.5 | V |
| $V_{\text {BE(sat)* }}$ | Base-Emitter <br> Saturation Voltage | $\mathrm{I}_{\mathrm{C}}=3 \mathrm{~A} \quad \mathrm{I}_{\mathrm{B}}=1 \mathrm{~A}$ |  |  | 1.5 | V |
| $\mathrm{h}_{\text {FE* }}{ }^{*}$ | DC Current Gain | $\begin{array}{lll} \hline \mathrm{I}=3 \mathrm{~A} & \mathrm{~V}_{\mathrm{CE}}=5 \mathrm{~V} & \\ \mathrm{I}_{\mathrm{C}}=3 \mathrm{~A} & \mathrm{~V}_{\mathrm{CE}}=5 \mathrm{~V} & \mathrm{~T}_{\mathrm{j}}=100^{\circ} \mathrm{C} \\ \hline \end{array}$ | $\begin{gathered} 4 \\ 2.5 \end{gathered}$ |  | 9 |  |
| $\begin{aligned} & \mathrm{t}_{\mathrm{s}} \\ & \mathrm{t}_{\mathrm{f}} \end{aligned}$ | RESISTIVE LOAD <br> Storage Time <br> Fall Time | $\begin{array}{ll} \hline \mathrm{V}_{\mathrm{CC}}=400 \mathrm{~V} & \mathrm{I}_{\mathrm{C}}=3 \mathrm{~A} \\ \mathrm{I}_{\mathrm{B} 1}=1 \mathrm{~A} & \mathrm{I}_{\mathrm{B} 2}=-1.5 \mathrm{~A} \end{array}$ |  | $\begin{aligned} & 1.8 \\ & 200 \end{aligned}$ | $\begin{aligned} & 2.7 \\ & 300 \end{aligned}$ | $\begin{aligned} & \mu \mathrm{s} \\ & \mathrm{~ns} \end{aligned}$ |
| $\begin{aligned} & \mathrm{t}_{\mathrm{s}} \\ & \mathrm{t}_{\mathrm{f}} \end{aligned}$ | INDUCTIVE LOAD <br> Storage Time Fall Time | $\mathrm{I}_{\mathrm{C}}=3 \mathrm{~A}$ $\mathrm{f}=15625 \mathrm{~Hz}$ <br> $\mathrm{I}_{\mathrm{B} \text { (end) }}=0.67 \mathrm{~A}$ $\mathrm{~L}_{\mathrm{C}}=1.3 \mathrm{mH}$ <br> $\mathrm{C}_{\text {snub }}=9.1 \mathrm{nF}$ $\mathrm{L}_{\text {bb(off) }}=8 \mu \mathrm{H}$ <br> $\mathrm{V}_{\mathrm{BE} \text { (off) }}=-4 \mathrm{~V}$ $\mathrm{~V}_{\mathrm{CC}}=150 \mathrm{~V}$ <br> Duty Cycle $=40 \%$  |  | $\begin{aligned} & 2.5 \\ & 400 \end{aligned}$ | $\begin{gathered} 6 \\ 500 \end{gathered}$ | $\begin{aligned} & \mu \mathrm{s} \\ & \mathrm{~ns} \end{aligned}$ |
| $V_{F}$ | Diode Forward Voltage | $\mathrm{I}_{\mathrm{F}}=3 \mathrm{~A}$ |  |  | 2.5 | V |

* Pulsed: Pulse duration = $300 \mu \mathrm{~s}$, duty cycle 1.5 \%

Safe Operating Area


Thermal Impedance


Derating Curve


Collector Emitter Saturation Voltage


Power Losses at 16 KHz


DC Current Gain


Base Emitter Saturation Voltage


Switching Time Inductive Load at 16 KHz (see figure 2)


Switching Time Resistive Load at 16 KHz


## BASE DRIVE INFORMATION

In order to saturate the power switch and reduce conduction losses, adequate direct base current $\mathrm{I}_{\mathrm{B} 1}$ has to be provided for the lowest gain $\mathrm{h}_{\mathrm{FE}}$ at $100{ }^{\circ} \mathrm{C}$ (line scan phase). On the other hand, negative base current lB2 must be provided to turn off the power transistor (retrace phase).
Most of the dissipation, in the deflection application, occurs at switch-off. Therefore it is essential to determine the value of $\mathrm{I}_{\mathrm{B} 2}$ which minimizes power losses, fall time $t_{f}$ and, consequently, $\mathrm{T}_{\mathrm{j}}$. A new set of curves have been defined to give total power losses, $\mathrm{t}_{\mathrm{s}}$ and $\mathrm{t}_{f}$ as a function of $\mathrm{I}_{\mathrm{B} 2}$ at 16 KHz scanning frequencies the optimum negative drive. The test circuit is illustrated in fig. 1.

Inductance $L_{1}$ serves to control the slope of the negative base current $\mathrm{I}_{\mathrm{B} 2}$ to recombine the excess carrier in the collector when base current is still present, this would avoid any tailing phenomenon in the collector current.
The values of $L$ and $C$ are calculated from the following equations:
$\frac{1}{2} L(I C)^{2}=\frac{1}{2} C\left(V_{C E F I V}\right)^{2}$
$\omega=2 \pi f=\frac{1}{\sqrt{L C}}$
Where $\mathrm{I}_{\mathrm{C}}=$ operating collector current, $\mathrm{V}_{\text {CEfly }}=$ flyback voltage, $f=$ frequency of oscillation during retrace.

Figure 1: Inductive Load Switching Test Circuits.


Figure 2: Switching Waveforms in a Deflection Circuit


| DIM. | mm |  |  | inch |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | 5.35 |  | 5.65 | 0.211 |  | 0.222 |
| C | 3.30 |  | 3.80 | 0.130 |  | 0.150 |
| D | 2.90 |  | 3.10 | 0.114 |  | 0.122 |
| D1 | 1.88 |  | 2.08 | 0.074 |  | 0.082 |
| E | 0.75 |  | 0.95 | 0.030 |  | 0.037 |
| F | 1.05 |  | 1.25 | 0.041 |  | 0.049 |
| F2 | 1.50 |  | 1.70 | 0.059 |  | 0.067 |
| F3 | 1.90 |  | 2.10 | 0.075 |  | 0.083 |
| G | 10.80 |  | 11.20 | 0.425 |  | 0.441 |
| H | 15.80 |  | 16.20 | 0.622 |  | 0.638 |
| L |  |  |  |  | 0.354 |  |
| L1 | 20.80 |  | 21.20 | 0.819 |  | 0.835 |
| L2 | 19.10 |  | 19.90 | 0.752 |  | 0.783 |
| L3 | 22.80 |  | 23.60 | 0.898 |  | 0.929 |
| L4 | 40.50 |  | 42.50 | 1.594 |  | 1.673 |
| L5 | 4.85 |  | 5.25 | 0.191 |  | 0.207 |
| L6 | 20.25 |  | 20.75 | 0.797 |  | 0.817 |
| N | 2.1 |  | 2.3 | 0.083 |  | 0.091 |
| R |  |  |  |  | 0.181 |  |
| DIA | 3.5 |  | 3.7 | 0.138 |  | 0.146 |



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